

785 nm Fabry-Perot Laser Diode, 90 mW

L785P090



Description

The L785P090 785 nm discrete laser diode is a compact light source suited to many applications. It comes in a Ø5.6 mm TO-can package with a C pin configuration.

Specifications

Absolute Maximum Ratings ^a				
LD Reverse Voltage (Max)	2 V			
PD Reverse Voltage	30 V			
Operating Case Temperature	-10 to 70 °C			
Storage Temperature	-40 to 85 °C			
Pin Code	С			



a. Please note that exceeding the absolute maximum ratings above may cause damage to the device.

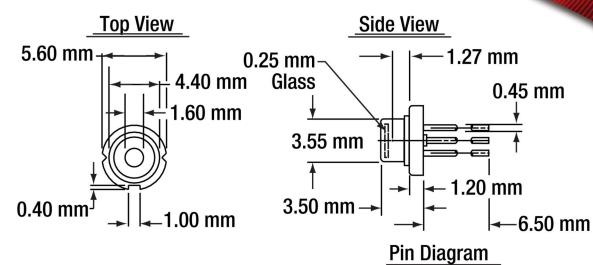
L785P090a					
	Symbol	Min	Typical	Max	
Center Wavelength ^b	λ_{P}	775 nm	785 nm	795 nm	
Optical Power	Po	-	90 mW	100 mW	
Threshold Current ^b	I _{TH}	-	35 mA	60 mA	
Operating Current ^b	I _{OP}	-	125 mA	165 mA	
Operating Voltage ^b	V _{OP}	1.5 V	2.0 V	2.6 V	
Slope Efficiency ^b	η	0.7 W/A	1.1 W/A	1.4 W/A	
Astigmatism	As	-	-	15 µm	
Beam Divergence Angle ^b	$\theta_{\mathbb{I}}$	6°	10°	14°	
	$\theta_{\scriptscriptstyle \perp}$	13°	17°	21°	
Beam Angle Deviation ^b	$\theta_{\mathbb{I}}$	-3°	-	3°	
	$\theta_{\scriptscriptstyle \perp}$	-3°	-	3°	
Emission Point Accuracy	ΔΧ	-60 µm	-	60 µm	
	ΔΥ	-60 µm	-	60 µm	
	ΔZ	-60 µm	-	60 µm	

a. T_{case} = 25°C

b. P₀=90 mW



Drawing



Bottom View



